

FOR PTO-1449 (Modified)
LIST OF PATENTS AND PUBLICATIONS FOR
APPLICANTS INFORMATION DISCLOSURE
STATEMENT

(Use several sheets if necessary)

ATTY. DOCKET NO.

3521.182

SERIAL NO.

10762,861

APPLICANT
SOMIT TALWAR, et al.

FILING DATE
January 22, 2004

GROUP
2813



REFERENCE DESIGNATION		U.S. PATENT DOCUMENTS										CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
EXAMINER INITIAL		DOCUMENT NUMBER								DATE	NAME			
TN	A	4	3	5	6	3	7	5		10-26-82	Josephy, et al.	219	121 LH	
	B	4	7	3	4	9	1	2		3-29-88	Soetbak, et al.	372	27	
	C	4	7	6	1	7	8	6		8-2-88	Baer	372	10	
	D	4	9	0	8	4	9	3		3-13-90	Susemihl	219	121.67	
	E	5	0	5	7	6	6	4		10-15-91	Johnson, et al.	219	121.69	
	F	6	2	0	8	6	7	3		3-27-01	Miyake	372	22	
	G	6	3	6	6	3	0	8		4-2-02	Hawryluk, et al.	347	256	
	H	6	7	4	7	2	4	5		6-8-04	Talwar, et al.	219	121.8	

FOREIGN PATENT DOCUMENTS

		DOCUMENT NUMBER								DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION	
														YES	NO

OTHER ART (Including Author, Title, Date, Pertinent Pages, Etc.)

TN	I	Naem, Boothroyd, Calder, <i>CW Laser Annealed Small-Geometry NMOS Transistors</i> , Mat. Res. Soc. Symp. Proc. Vol. 23 (1984) pp 229-234.
	J	Goetzlich, Tsien, Ryssel, <i>Relaxation Behavior of Metastable AS and P Concentrations in SI After Pulsed and CW Laser Annealing</i> , Mat. Res. Soc. Symp. Proc. Vol. 23 (1984) pp 235-240

EXAMINER

T. N. GUYEN

DATE CONSIDERED

12/28/05

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.